

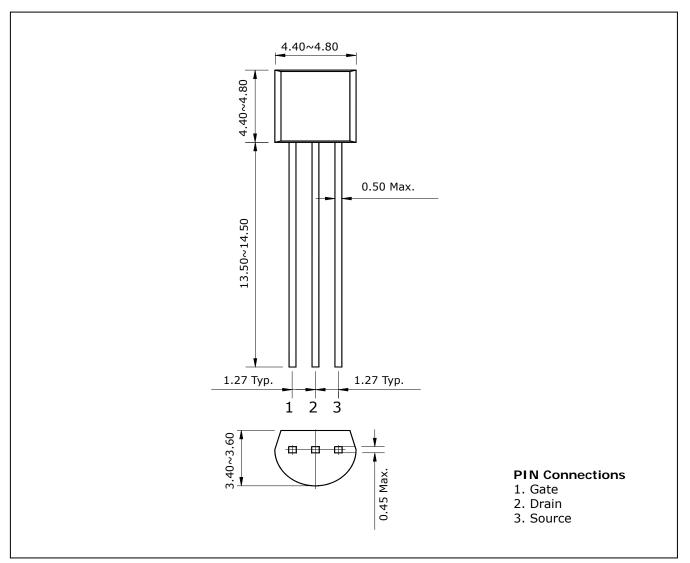
STK03Y60

Advanced Power MOSFET

unit : mm

SWITCHING REGULATOR APPLICATIONSFeatures• High Voltage: BV_{DSS} =600V(Min.)• Low C_{rss} : C_{rss} =4pF(Typ.)• Low C_{rss} : C_{rss} =4pF(Typ.)• Low gate charge : Qg=12nC(Typ.)• Low $R_{DS(on)}$: $R_{DS(on)}$ =5.5 Ω (Typ.)Ordering InformationType NO.MarkingPackage CodeSTK03Y60STK03Y60

Outline Dimensions



TENTATIVE

STK03Y60

Absolute maximum ratings

| Absolute maximum ratings | (Ta=25°C) | | | |
|--------------------------------|-----------|------------------|---------|------|
| Characteristic | | Symbol | Rating | Unit |
| Drain-source voltage | | V_{DSS} | 600 | V |
| Gate-source voltage | | V_{GSS} | ±30 | V |
| Drain current (DC) ** | | I _D | 0.3 | А |
| Drain current (Pulsed) * | | I_{DP} | 1.2 | A |
| Total Power dissipation ** | | P _D | 625 | mW |
| Avalanche current (Single) | 2 | I _{AS} | 0.3 | А |
| Single pulsed avalanche energy | 2 | E _{AS} | 53 | mJ |
| Avalanche current (Repetitive) | 1 | I _{AR} | 0.3 | А |
| Repetitive avalanche energy | 1 | E _{AR} | 11 | mJ |
| Junction temperature | | Tյ | 150 | °C |
| Storage temperature range | | T _{stg} | -55~150 | |

* Limited by maximum junction temperature

** Device mounted on a glass-epoxy board

| Characteristic | | Symbol | Typ. Max | | Unit | |
|--------------------|------------------|-----------------------------|----------|-----|------|--|
| Thermal resistance | Junction-ambient | $R_{th(\mathtt{J-a})}^{**}$ | - | 200 | °C/W | |

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| N-CH Electrical Character | (Ta=25°C) | | | | | |
|----------------------------------|------------------------|--|------|------|------|------|
| Characteristic | Symbol Test Condition | | Min. | Тур. | Max. | Unit |
| Drain-source breakdown voltage | BV _{DSS} | I_{D} =250 μ A, V_{GS} =0 | 600 | - | - | V |
| Gate threshold voltage | $V_{GS(th)}$ | $I_D=250\mu A$, $V_{DS}=V_{GS}$ | 3.0 | - | 5.0 | V |
| Drain-source cut-off current | I _{DSS} | V_{DS} =600V, V_{GS} =0V | - | - | 1 | μA |
| Gate leakage current | I _{GSS} | V_{DS} =0V, V_{GS} =±30V | - | - | ±100 | nA |
| Drain-source on-resistance | R _{DS(ON)} | V_{GS} =10V, I_{D} =150mA | - | 5.5 | 8.5 | Ω |
| Forward transfer conductance ④ | g _{fs} | V_{DS} =10V, I_{D} =150mA | - | 0.32 | - | S |
| Input capacitance | Ciss | V _{GS} =0V, V _{DS} =25V, | - | 130 | - | pF |
| Output capacitance | Coss | f=1MHz | - | 20 | - | |
| Reverse transfer capacitance | Crss | | - | 4 | - | |
| Turn-on delay time | t _{d(on)} | | - | 5.5 | - | ns |
| Rise time | t _r | V _{DD} =300V, I _D =0.3A R _G =25Ω | - | 5 | - | |
| Turn-off delay time | $t_{d(off)}$ | 3(4) | - | 13 | - | |
| Fall time | t _f | | - | 28 | - | |
| Total gate charge | Qg | V _{DD} =300V, V _{GS} =10V | - | 12 | 18 | nC |
| Gate-source charge | Q_gs | I _D =0.3A | - | 2.5 | 3.8 | |
| Gate-drain charge | Q_gd | 34 | - | 3.0 | 4.5 | |

Source-Drain Diode Ratings and Characteristics

Symbol **Test Condition** Characteristic Min Тур Max Unit Source current 0.3 \mathbf{I}_{S} _ Integral reverse diode -А in the MOSFET Source current(Plused) 1 I_{SM} 1.2 --(4) Forward voltage V_{GS}=0V, I_S=0.3A 0.7 1.2 V V_{SD} _ Reverse recovery time t_{rr} 260 _ ns - $I_s=0.3A, V_{gs}=0V$ dis/dt=80A/us Reverse recovery charge 3.5 uC Q_{rr} _ _

Note;

- ① Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature
- 2 L=109mH, I_{AS}=0.3A, V_{DD}=50V, R_G=25 Ω
- ③ Pulse Test : Pulse Width < 300us, Duty cycle $\leq 2\%$
- (4) Essentially independent of operating temperature

(Ta=25°C)

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